



1 CHANNEL LOW CAPACITANCE TVS DIODE ARRAY

Features

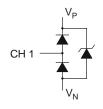
- IEC 61000-4-2 (ESD): Air ±15kV, Contact ±8kV
- 1 Channel of ESD Protection
- Low Channel Input Capacitance of 0.85pF Typical
- Typically Used at High Speed Ports such as USB 2.0, IEEE1394, Serial ATA, DVI, HDMI, PCI
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish annealed over Alloy 42 leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.006 grams (approximate)







Pin Configuration

3

Device Schematic

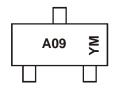
Ordering Information (Note 4)

Part Number	Case	Packaging
D1213A-01W-7	SOT323	3000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com.

Marking Information



A09 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: Z = 2012)M = Month (ex: 9 = September)

Date Code Key

Year	201	1	2012		2013	20	14	2015		2016	2	2017
Code	Υ		Z		Α	[3	С		D		Е
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	Conditions
Operating Supply Voltage	V _P - V _N	6.0	V	-
DC Voltage at any Channel Input	-	$(V_N - 0.5)$ to $(V_P + 0.5)$	V	-
Peak Pulse Current	I _{PP}	5	Α	8/20µs, Per Figure 3
ESD Protection – Contact Discharge	$V_{ESD_Contact}$	±8	kV	Standard IEC 61000-4-2
ESD Protection – Air Discharge	V_{ESD_Air}	±15	kV	Standard IEC 61000-4-2

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P_{D}	200	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ hetaJA}$	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

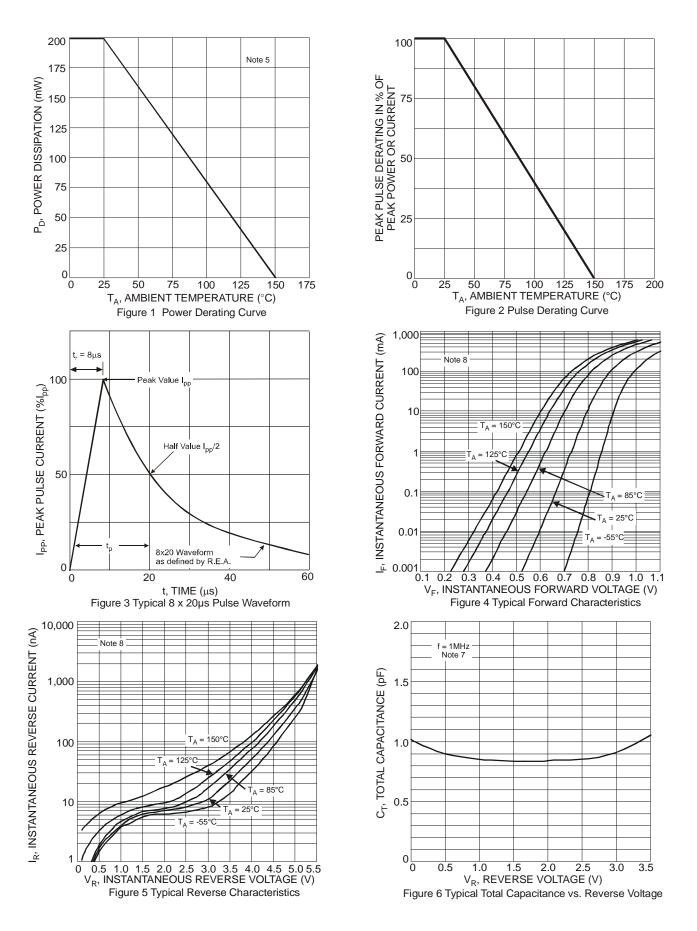
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
Operating Supply Voltage	V _P	-	3.3	5.5	V	-
Operating Supply Current (Note 6)	lρ	-	-	8.0	μΑ	$(V_P - V_N) = 3.3V$
Channel Leakage Current (Note 6)	I _R	-	±0.1	±1.0	μΑ	$V_P = 5V$, $V_N = 0V$
Reverse breakdown voltage	V_{BR}	6.0	-	-	V	$I_R = 1mA$
Clamping Voltage, Positive Transients	V _{CL1}	-	10.0	-	V	$I_{PP} = 1A$, $t_p = 8/20 \mu s$
Clamping Voltage, Negative Transients	V _{CL2}	-	-1.7	-	V	$I_{PP} = -1A, t_p = 8/20 \mu s$
Forward Voltage for Top Diode	V _{FD1}	0.60	0.80	0.95	V	$I_F = 8mA$, CH1 to V_P
Forward Voltage for Bottom Diode	V _{FD2}	0.60	0.80	0.95	V	I _F = 8mA, V _N to CH1
Dynamic Resistance	R_{DYN}	ı	0.9	-	Ω	$I_{PP} = 1A$, $t_p = 8/20 \mu s$
Channel Input Capacitance	Ст	-	0.85	1.2	pF	$V_{IN} = 1.65V, V_P = 3.3V, V_N = 0V, f = 1MHz$

Notes:

- 5. Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes, Inc. suggested pad layout AP02001, which can be found on our website at http://www.diodes.com.
- 6. Short duration pulse test used to minimize self-heating effect.
- 7. Measured from CH1 to V_N.
- 8. Measured from V_P to V_N.
- 9. For information on the impact of Diodes' USB 2.0 compatible ESD protectors on signal integrity including eye diagram plots, please refer to AN77 at the following URL: http://www.diodes.com/destools/appnote_dnote.html.

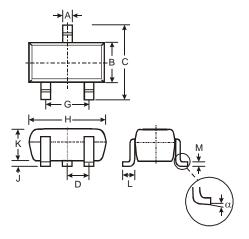






Package Outline Dimensions

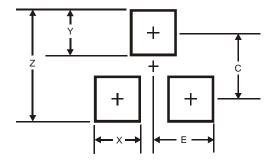
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT323							
Dim	Min	Max	Тур				
Α	0.25	0.40	0.30				
В	1.15	1.35	1.30				
С	2.00	2.20	2.10				
D	-	-	0.65				
G	1.20	1.40	1.30				
Н	1.80	2.20	2.15				
J	0.0	0.10	0.05				
K	0.90	1.00	1.00				
L	0.25	0.40	0.30				
М	0.10	0.18	0.11				
α	0°	8°	-				
All Dimensions in mm							

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.8
Х	0.7
Y	0.9
С	1.9
Е	1.0



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